

ABSTRACT OF THE DISCLOSURE

A method of preventing the scrapping of semiconductor substrates due to improper deposition of thin films in a film vaporization system is disclosed. This is thin accomplished by providing a method of self-calibrating and testing the flow of liquid precursors in the vaporization system prior to the start of the deposition process. vaporization of the liquid precursor in the deposition chamber and the concomitant pressure change in the chamber This correlation is then used as a real are correlated. time monitoring mechanism for self-calibrating and testing the flow of liquid precursors through the vaporization system. That the pressure change due to vaporization in the the key parameter, the thin film chamber is used as deposition is hence monitored by that parameter which directly predicts the film deposition characteristics. Consequently, each thin film run is assured of a successful run.